

### Millimeter-wave surface impedance of $\text{YBa}_2\text{Cu}_3\text{O}_7$ thin films

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We have measured the millimeter wave ( $f=101.3$  GHz) surface impedance of various  $\text{YBa}_2\text{Cu}_3\text{O}_7$  films deposited on various substrates.  $R_s(T)$  rapidly decreases below  $T_c$  and is, at  $T=77$  K, orders of magnitude smaller than that found generally in ceramic and thin-film specimens prepared by other groups. A comparison is given with predictions of the two-fluid model and the BCS theory.

The electromagnetic response of various high-temperature superconductors has been thoroughly explored using a variety of experimental techniques. Early measurements<sup>1</sup> of the penetration depth  $\lambda(T)$  have indicated deviations from the BCS behavior, while recent experiments<sup>2</sup> performed on single crystals are in agreement with conventional pairing. Optical experiments<sup>3</sup> are controversial, and gap values both in agreement with weak-coupling BCS theory and far exceeding this limit have been frequently reported in the literature.

In this Rapid Communication we present experimental results and analysis of the surface impedance  $Z_s$ . When  $\xi_0 \ll \lambda$ , as it is for the oxide superconductors, the surface impedance is related to the complex conductivity  $\sigma = \sigma_1 - j\sigma_2$  by

$$Z_s = \left( \frac{j\mu_0\omega}{\sigma_1 - j\sigma_2} \right)^{1/2} = -R_s + jX_s. \quad (1)$$

Here  $\mu_0$  is the permeability of free space and  $\omega/2\pi$  the measurement frequency.  $R_s$  and  $X_s$  are the surface resistance and the surface reactance, respectively.<sup>4</sup>

The surface resistance  $R_s(T)$  has been measured by various groups on both ceramic, thin-film, and single-crystal specimens.<sup>4</sup> Ceramic and thin-film materials usually have substantial residual surface resistance  $R_s(T=0)$ , and  $R_s(T)$  also displays drastic deviations from the BCS behavior [i.e., linear temperature dependence of  $R_s(T)$  below 50 K]. The residual losses are most probably due to imperfections, grain boundaries, etc., which can be modeled<sup>5</sup> in terms of a network of Josephson junctions. The power-law temperature dependence<sup>6</sup> of  $R_s(T)$  and  $X_s$ , however, have not been accounted for. Experiments on high-quality single crystals<sup>7</sup> and oriented thin

films<sup>8</sup> show a significant reduction of  $R_s(T)$  in the superconducting state where the experiments are limited to the immediate vicinity of  $T_c$  due to a lack of sensitivity associated with the relatively low measurement frequency. Because of this, and also because of complications arising from the finite thickness of the films, a detailed comparison with calculations has not been performed.

Our experiments have been conducted on  $\text{YBa}_2\text{Cu}_3\text{O}_7$  films deposited on  $\text{SrTiO}_3$  and  $\text{LaAlO}_3$  substrates by means of a pulsed-laser deposition process described elsewhere.<sup>9,10</sup> The substrate surface during deposition was kept at temperatures between 650 and 750°C with a background oxygen pressure of 220 mTorr. These *in situ* deposited films, without post annealing, exhibited zero resistance transition temperatures of over 91 K with onset at 93 K and dc critical current densities of over  $5 \times 10^6$  A/cm<sup>2</sup> at 77 K. The films have a crystalline structure close to that of bulk single crystals as measured by an ion channeling technique,<sup>11</sup> showing a minimum yield of 3%. This represents nearly perfect *c*-axis alignment.

The surface resistance  $R_s(T)$  and surface reactance  $X_s(T)$  has been measured in a cylindrical copper  $\text{TE}_{011}$  transmission cavity operating at 101.3 GHz. In this configuration, currents flow in the Cu-O planes, and consequently the measured  $R_s$  and  $X_s$  are related to the in-plane properties. We measure the resonance frequency and bandwidth as a function of temperature using the superconducting film or a polished copper plate as the bottom of the cavity. The difference between the sample surface impedance and the copper surface impedance is proportional to the change in the bandwidth  $\Delta W = W_{\text{sample}} - W_{\text{Cu}}$  and the resonance frequency  $\Delta f = f_{\text{sample}} - f_{\text{Cu}}$ :

$$\Delta Z_s = \Delta R_s + j\Delta X_s = \gamma^{-1}(\Delta W/2 - j\Delta f), \quad (2)$$

where  $\gamma$  is the resonator constant for the mode. With  $R_s$  (copper) known,  $R_s$  ( $\text{YBa}_2\text{Cu}_3\text{O}_7$ ) can be evaluated. Our experiments on the reactance  $X_s$  will be reported later. Here we describe our experiments on the surface resistance  $R_s$ .

In Fig. 1(a),  $R_s(T)$  is shown for two films of different thicknesses, deposited on different substrates. Data were taken at approximately 1-K intervals and the curves displayed in the figure represent the overall temperature dependence observed. In both cases  $R_s$  sharply decreases at  $T_c$  with no measurable temperature variation below about 75 K. Figure 1(b) shows the low temperature (below 70 K) variation of  $R_s(T)$  for the two films of Fig. 1(a). Within our experimental resolution,  $R_s$  is unmeasurable below 70 K, and more detailed experiments employing superconducting cavities will be required to establish the upper limit of  $R_s$  at low temperatures. More precisely, the experiments indicate a variable but small re-

sidual loss [seen in Fig. 1(b)] at temperatures below approximately 70 K. The origin of this, and whether it can be separately interpreted as surface resistance has not been resolved. This residual loss has been subtracted from our result and we are focusing on the temperature-dependent part of  $R_s$ ,  $R_s(T)$ .

The film thickness is a factor of 2 to 3 smaller than the skin depth  $\delta$  in the normal state

$$\left[ \rho_n(100 \text{ K}) = 50 \mu\Omega \text{ cm}, \delta = \left( \frac{2\rho}{\mu_0\omega} \right)^{1/2} = 1.1 \mu\text{m} \right]$$

and our experiments indicate substantial losses associated with leakage through the films in the normal state. First, the film with a smaller thickness,  $d = 4000 \text{ \AA}$ , exhibits an apparent normal-state  $R_s$  value approximately twice that of the normal-state  $R_s$  measured on a thicker,  $d = 6000 \text{ \AA}$  film. Both exceed the value which can be calculated using  $R_s = (\mu_0\omega\rho_n/2)^{1/2} = 0.45 \Omega$  for  $\omega/2\pi = 101.3 \text{ GHz}$  and  $\rho_n = 50 \mu\Omega \text{ cm}$ . Using this value, and the measured  $R_s$  values at  $T_c$ , the amount of leakage can be estimated. Second, for films deposited on  $\text{SrTiO}_3$  substrate, oscillations in  $R_s(T)$  are seen. This has been shown<sup>6</sup> to be due to standing waves associated with the  $\text{SrTiO}_3$  substrate which has a strongly temperature-dependent dielectric constant. This phenomenon can also be used to establish the amount of leakage.<sup>6</sup> Both observations indicate that while leakage is substantial in the normal state, in the superconducting state the relevant length scale is the penetration depth  $\lambda$ , and below about  $0.98T_c$  negligible leakage is expected within our experimental error.

In Figs. 2-4, the superconducting surface resistance  $R_s$ , normalized to the normal-state surface resistance value

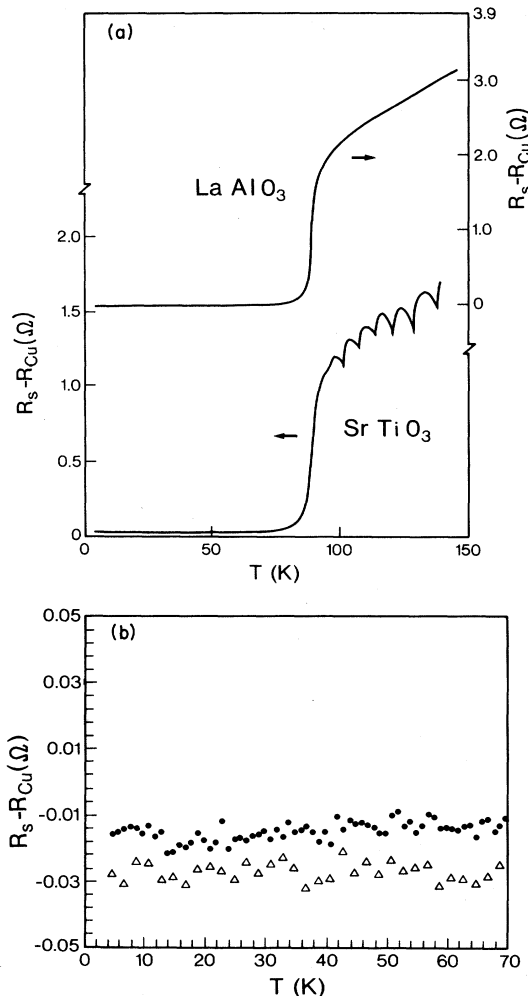


FIG. 1. (a) Temperature dependence of  $R_s - R_{\text{Cu}}$  in  $\text{YBa}_2\text{Cu}_3\text{O}_7$  thin films on  $\text{LaAlO}_3$  (4000- $\text{\AA}$ -thick) and  $\text{SrTiO}_3$  (6000- $\text{\AA}$ -thick) substrates at 101.3 GHz. (b) Temperature dependence of  $R_s - R_{\text{Cu}}$  below 70 K for the films in (a). The triangles represent the 4000- $\text{\AA}$ -thick  $\text{LaAlO}_3$  thin film and the circles represent the 6000- $\text{\AA}$ -thick  $\text{SrTiO}_3$  thin film.

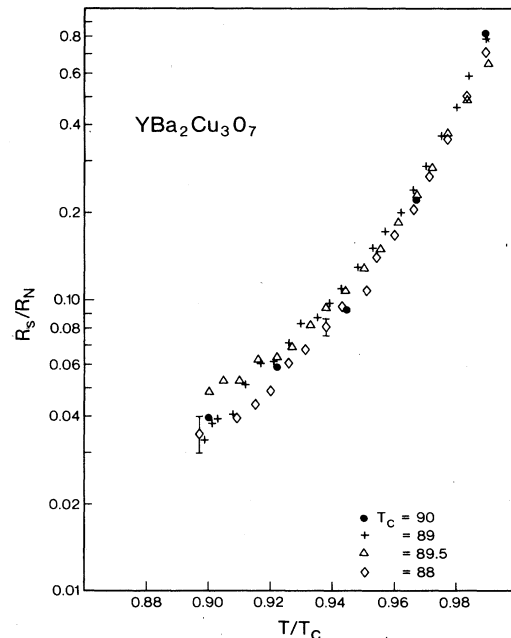


FIG. 2. Temperature dependence of the reduced surface resistance  $R_s/R_N$  vs reduced temperature  $T/T_c$  for the various  $\text{YBa}_2\text{Cu}_3\text{O}_7$  thin films at 101.3 GHz.  $R_N = 0.45 \Omega$  corresponding to  $\rho_n = 50 \mu\Omega \text{ cm}$ .

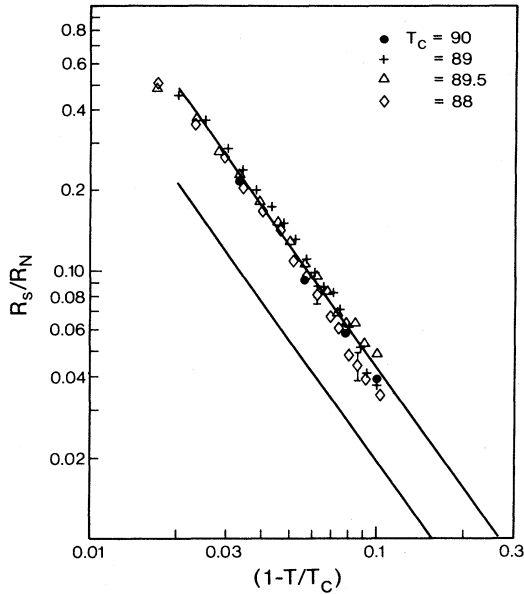


FIG. 3. Temperature dependence of the normalized surface resistance  $R_s/R_N$  vs reduced temperature  $1 - T/T_c$  of the various  $\text{YBa}_2\text{Cu}_3\text{O}_7$  films at 101.3 GHz. The solid curves represent the predictions of the two-fluid model. The parameters used are  $\sigma_n^{-1} = 50 \mu\Omega\text{cm}$  and  $\lambda(0) = 1500 \text{ \AA}$  for the lower curve and  $\lambda(0) = 1970 \text{ \AA}$  for the upper curve. See text for detailed discussion.

$R_N = 0.45 \Omega$  at  $T = T_c$ , is displayed versus the reduced temperature  $T/T_c$  and  $1 - T/T_c$ . Also included in Figs. 3 and 4 are several theoretical curves that will be discussed later. Since it is difficult to determine  $T_c$  accurately from our experiments due to leakage through the films near  $T_c$ , and no other independent method was used to determine  $T_c$ , we have treated it as a free parameter, and the values used are displayed in the figures. They are in agreement with the general trend of observing slightly reduced  $T_c$  values in films, as compared with single crystals. Several features of Figs. 2, 3, and 4 are of importance. First, the temperature dependence observed is similar for the three films measured, indicating an intrinsic behavior. Second, a specimen measured twice with a time difference of about one month with the sample stored in air at room temperature (points  $\bullet$  and  $+$ ) shows little degradation, as evidenced only by a slight decrease of the transition temperature. We also note that  $R_s$  of the films investigated is significantly smaller than all other reported values (except for Ref. 8) that we are aware of.

The superconducting copper oxides differ from conventional superconductors in many ways. In addition to having significantly higher transition temperatures, they are anisotropic with the one-electron transfer in the  $c$  direction being much weaker than that in the  $a$  and  $b$  directions.<sup>12</sup> Furthermore, the coherence length in these materials is of the order of tens of angstroms<sup>13</sup> which is much shorter than the penetration depth of the magnetic field which is of the order of several thousand angstroms. This is in contrast with conventional clean superconductors in which the coherence length is typically much larger than

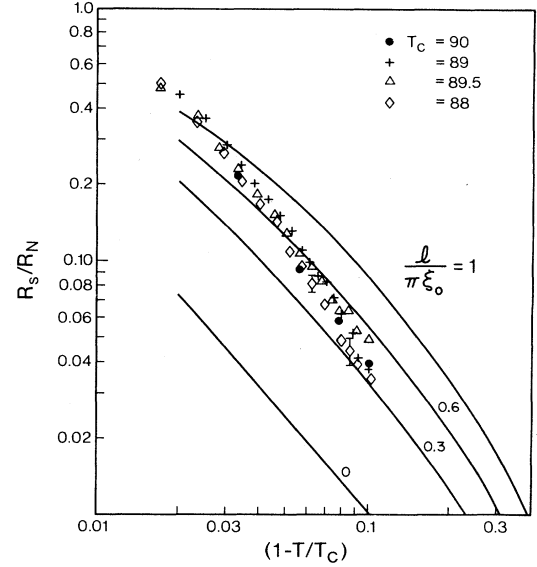


FIG. 4. Temperature dependence of the normalized surface resistance  $R_s/R_N$  vs reduced temperature  $1 - T/T_c$  of the various  $\text{YBa}_2\text{Cu}_3\text{O}_7$  films at 101.3 GHz. The solid curves represent the predictions of the BCS theory with the ratio  $l/\pi\xi_0 = 0, 0.3, 0.6, 1.0$ , and  $2\Delta(0)/k_B T_c = 3.52$ .

the penetration depth.<sup>14</sup> For this reason, the electromagnetic response is described by a local London relation. Here we discuss two models for the surface impedance of a  $c$ -axis oriented film. First we consider a two-fluid model with

$$\sigma_1 = \sigma_n \left( \frac{T}{T_c} \right)^4, \quad (3)$$

and

$$\sigma_2 = \frac{1}{\mu_0 \omega \lambda^2(T)} = \frac{1 - (T/T_c)^4}{\mu_0 \omega \lambda^2(0)}. \quad (4)$$

For a  $c$ -axis normal oriented film,  $\sigma_n$  is the  $ab$  plane normal-state conductivity and  $\lambda(0)$  is the zero-temperature  $ab$  penetration depth. Taking  $\sigma_n = 2 \times 10^6 / \Omega\text{m}$  corresponding to  $\rho_n = 50 \mu\Omega\text{cm}$  and  $\lambda(0) = 1500 \text{ \AA}$ ,<sup>2,15</sup> one finds that at 100 GHz,  $\sigma_1/\sigma_2 \ll 1$  over the temperature region of interest,<sup>16</sup> so that Eq. (1) can be expanded, giving

$$\frac{R_s}{R_N} = \frac{1}{\sqrt{2}} [\mu_0 \omega \sigma_n \lambda^2(0)]^{3/2} \frac{(T/T_c)^4}{[1 - (T/T_c)^4]^{3/2}}. \quad (5)$$

In the temperature region near  $T_c$  where  $R_s$  was measured, this reduces to

$$\frac{R_s}{R_N} \cong 6.06 \times 10^{-4} \left( 1 - \frac{T}{T_c} \right)^{-3/2}, \quad (6)$$

which is plotted as the lower curve in Fig. 3. If we take  $\lambda(0) = 1970 \text{ \AA}$  we obtain the upper curve, which passes through the data.

The second approach that we have used to analyze these results is to calculate  $\sigma$  within the framework of the BCS

theory. For a  $c$ -axis oriented film, we neglect the electron transfer between the planes, so that only the component of the wave vector of the electromagnetic field parallel to the layers enters. It is effectively zero for the micro- and millimeter waves of interest, so that the electromagnetic kernel relating the current density  $\mathbf{j}$  to the vector potential  $\mathcal{A}$  is evaluated with  $\mathbf{q} = 0$ .<sup>17</sup> Thus the electromagnetic response is described by Eq. (1) with  $\sigma$  depending on  $l/\pi\xi_0$ ,  $2\Delta(0)/k_B T_c$ ,  $\omega/\Delta(0)$ , and  $T/T_c$ . Here  $l$  is the mean free path, which we assume to be limited by elastic scattering due to impurities, and  $\xi_0$  is the zero-temperature coherence length  $\hbar v_F/\pi\Delta(0)$ . It is of course an open question as to whether such a BCS analysis is appropriate and in particular whether the scattering lifetime, which probably arises from the underlying dynamics, can be approximated by an elastic scattering mean free path even over the relatively narrow temperature range of this experiment.

Results obtained from the BCS theory with  $2\Delta(0)/k_B T_c = 3.52$  are compared with the experimental data in Fig. 4. In the dirty limit  $l/\pi\xi_0 \ll 1$ , the conductivity which enters Eq. (1) is given by the Mattis-Bardeen result<sup>18</sup> appropriate for our local electrodynamics. The temperature dependence of  $R_s/R_N$  in the dirty limit is shown as the lowest curve in Fig. 4. An estimate of  $l/\xi_0$  can be obtained from

$$\sigma_n \lambda_L^2(0) = \frac{\tau}{\mu_0} = \frac{l}{\pi\xi_0} \left[ \frac{k_B T_c}{2\Delta(0)} \right] \frac{2\hbar}{\mu_0 k_B T_c}. \quad (7)$$

Taking  $\sigma_n^{-1} = 50 \mu\Omega \text{ cm}$ ,  $T_c = 90 \text{ K}$ ,  $2\Delta(0)/k_B T_c = 3.52$ , and  $\lambda_L \cong 1500 \text{ \AA}$  gives<sup>19</sup>  $l/\pi\xi_0 \cong 1.2$ . Results for various values of  $l/\pi\xi_0$ , keeping  $2\Delta(0)/k_B T_c = 3.52$ , are shown as

the other solid curves. Even for the best case,  $l/\pi\xi_0 = 0.6$ , we see that the fit is not as good as that of the two-fluid model. The calculated BCS curve has a smaller slope than the experimental data. We note that for larger values of  $2\Delta(0)/k_B T_c$ , the BCS curve decreases more rapidly as  $T/T_c$  decreases, and the fit is slightly better. At present we believe that better data on both  $R_s$  and  $X_s$ , particularly at low temperatures, is required for a meaningful comparison with a stronger-coupling theory in which  $2\Delta(0)/k_B T_c$  is larger.

In summary, we have measured the temperature dependence of the surface resistance of several  $\text{YBa}_2\text{Cu}_3\text{O}_7$  superconducting thin films on different substrates. Our results are compared with those of the two-fluid model and the BCS theory, including the mean-free-path effect. The two-fluid model can account for the slope, but to have the correct magnitude with  $\rho_n = 50 \mu\Omega \text{ cm}$  at  $T_c$ , it requires  $\lambda(0) \cong 1970 \text{ \AA}$ , which is somewhat larger than the currently accepted value of the zero-temperature penetration depth  $\lambda(0) = 1500 \text{ \AA}$ . On the other hand, the BCS theory can account for the correct magnitude of  $R_s/R_N$  using  $2\Delta(0)/k_B T_c = 3.52$  and a reasonable value of  $l/\pi\xi_0 = 0.6$ . However, it predicts a slower decrease in  $R_s/R_N$  as the temperature is reduced than that which is observed. It will be interesting to make a similar study of the microwave reactance, which is currently in progress.

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<sup>16</sup>Here  $T$  is relative near  $T_c$  but far enough below  $T_c$  that  $\sigma_2$  is large compared to  $\sigma_1$ .

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<sup>19</sup>Here of course, we are lumping the inelastic and elastic scattering together. We are also using the clean limit result  $\lambda(0) = \lambda_L(0)$  which is reasonable since we find  $l/\xi_0 \geq 1$ .